Hybrid Catalyst Composed of Reduced Graphene Oxide/Cu₂S Quantum Dots as a Transparent Counter Electrode for Dye Sensitized Solar Cells

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1 Experimental detail

1.1 Synthesis of the hybrid catalyst of RGO/Cu₂S QDs hybrid.

GO sheets for the RGO-Cu₂S QDs hybrid in this work were prepared by the oxidation and exfoliation of natural graphite using an improved Hummers' method.

Before the hybrid catalyst synthesis, 20 mg freeze-dried GO was added to 30 ml ethanol and the mixture were sonicated for 2 h until the GO was homogeneously dispersed in the solution. In a typical experiment, 1 mmol copper acetylacetonate (Cu (acac) $_2$), 15 ml oleylamine (OLA), and 30 ml GO-ethanol solution were added into a three-necked flask (100 ml) at room temperature, followed by sonication for 30 min. After this, the mixture was heated to 120 °C and kept at this temperature for 30 min, while alternating between a vacuum (obtained using a vacuum pump) and a N₂ atmosphere (by bubbling N₂ through the mixture). Next, the GO-Cu(acac)₂-OLA solution was heated to 200 °C and 5 ml of a sulfur-OLA solution (obtained by stirring 0.5 mmol sulfur powder and 5 ml OLA at 60 °C under a N₂ atmosphere) was injected and the mixture was kept at the same temperature under a N₂ atmosphere, with vigorous stirring, for 1 h. Finally, after cooling, the as-synthesized RGO–Cu₂S QD hybrids were purified by repeated centrifugation and then washed using a mixture of solvent (chloroform) and anti-solvent (ethanol). The final product was redispersed in ethanol for deposition on the FTO glass by spray coating approach.

1.2 Preparation of counter electrodes:

Moreover, the RGO/Cu₂S QDs hybrid was prepared by 3 mg as-prepared RGO/Cu₂S QDs hybrid dispersed in 10 mL ethanol using ultrasonication, and a thin layer of RGO/Cu₂S QDs hybrids were deposited on FTO glass substrate (SnO₂:F glass, 8 Ω /sq) by spraying coating method using an airbrush. The Cu₂S QDs and RGO counter electrode was prepared in the same way. Before fabrication of the DSSCs devices, the electrodes were sintered at 400 °C in an Ar atmosphere for 2 h.

To prepare Pt CEs, 50 μ L of H₂PtCl₆ in ethanol was drop-cast on FTO glass substrates, followed by heat treatment at 380 °C for 30 min

1.3 Fabrication of Dye-sensitized solar cells:

A TiO₂ film loaded on the FTO glass with dense transparent TiO₂ nanoparticle film (~13 µm in

thickness, 18 nm in diameter) and a scattering layer (~5 μ m in thickness, 400 nm in diameter) were prepared by a screen-printing method onto Fluorine doped Tin Oxide (FTO) glass, respectively. The substrate was sintered at 500 °C for 1 h and cooled to 100 °C to generate the anatase nanocrystals. After sintering, the TiO₂ electrode was immersed in TiCl₄ (40 mM) aqueous solution at 70 °C for 30 min. The film was then annealed at 450 °C for 30 min. In the following step, the mesoporous TiO₂ was sensitized in N719 solution for 24 hours, the photoanode was sealed with a counter electrode by Surlyn films (40 µm in thickness) by Hot-press machine. Further, an electrolyte which consists an acetonitrile solution of 0.6 M (1,2-dimethyl- 3-propyl) imidazolium iodide, 0.05 M I₂, 0.5 M TBP, and 0.1 M LiI was to backfill through the hole in the counter electrodes of all the cells and then sealed them with a Surlyn film covered with a thin glass slide under heat.

1.4 Characterization and Measurement:

Morphologies of as-obtained products were observed on a field emission scanning electron microscopic (FESEM, FEI Sirion 200). Transmission electron microsopy (TEM, JEOL JEM-2100F) images were obtained under an acceleration voltage of 200 kV. UV-*vis* absorption spectra were recorded using a Hitachi U-4100 (Japan) spectrophotometer. The crystal structures of the counter electrode samples were characterized by powder X-ray diffrac-tion (XRD) using a Goniometer Ultima IV (185 nm) diffractometer with Cu K_{α} radiation, excited at 40 kV and 40 mA. Raman spectra were taken on a DXR Raman Microscope with an excitation length of 532nm.

Electrochemical impedance spectroscopy (EIS) measurements were obtained with an impedance analyzer (Zahner IM6, Germany) at zero bias potential. The impedance studies were carried out simulating open-circuit conditions in the atmosphere, and AC potential amplitude of 5 mV over a frequency range of $0.01-10^5$ Hz in the dark conditions. The resultant impedance spectra were analyzed by means of the Z-view software. The Tafel polarization curves were measured using the Zahner electrochemical workstation system at s scan rate of 10 mV s⁻¹. Additionally, all the EIS and Tafel measurements were based on a symmetric conguration consisting of two identical electrodes filled with the redox electrolyte which was to used in the DSSCs. Cyclic voltammetry (CV) were executed in a three electrode system with different CEs as the working electrode, a platinum wire as the counter electrode, and Ag/Ag⁺ electrode as the pseudo reference electrode, which was

calibrated with a ferrocene solution after the CV measurements, at a scanning rate of 50 mVs⁻¹. The electrode was dipped in an anhydrous acetonitrile solution containing 0.1 mM LiClO₄, 10 mM LiI, and 1 mM I_2 .

For the photovoltaic measurements, devices were equipped with a UV cut-off filter and masked with a thin metal mask to give an active area of 0.25 cm². *J-V* curves of the DSSCs were measured with a digital source meter (Keithley 2400) under simulated solar illumination at 100 mW cm⁻², AM1.5 G standard (Wacom, Japan). During I-V measurements, a black mask was used with an aperture area of 0.25 cm⁻².

2 Supporting Information



Fig.S1 (a) TEM image of Cu₂S QDs; (b) TEM image of graphene oxide; (c) AFM imagines of graphene oxide; (d) EDS of RGO/Cu₂S QDs hybrid.



Fig.S2 SEM imagines of (a) Top view and (b) cross-section of Cu_2S QDs.



Fig.S3 The thickness of RGO/Cu₂S hybrid on FTO glass measured by a surface profiler.